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November 2013

## FDD850N10LD BoostPak (N-Channel PowerTrench<sup>®</sup> MOSFET + Diode) 100 V, 15.3 A, 75 mΩ

#### **Features**

- $R_{DS(on)}$  = 61 m $\Omega$  (Typ.) @  $V_{GS}$  = 10 V,  $I_D$  = 12 A
- R<sub>DS(on)</sub> = 64 mΩ (Typ.) @ V<sub>GS</sub> = 5.0 V, I<sub>D</sub> = 12 A
- Low Gate Charge (Typ. 22.2 nC)
- Low C<sub>rss</sub> (Typ. 42 pF)
- · Fast Switching
- 100% Avalanche Tested
- Improved dv/dt Capability
- RoHS Compliant

### Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's PowerTrench<sup>®</sup> process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

The NP diode is hyperfast rectifier with low forward voltage drop and excellent switching performance.

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#### Applications

- LED Monitor Backlight
- LED TV Backlight
- LED Lighting
- Consumer Appliances, DC-DC converter (Step up & Step down)

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#### Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

Symbol	Parameter			FDD850N10LD	Unit
V <sub>DSS</sub>	Drain to Source Voltage			100	V
V <sub>GSS</sub>	Gate to Source Voltage			±20	V
I <sub>D</sub> Drain Current		- Continuous (T <sub>C</sub> = 25 <sup>o</sup> C)	15.3	Α	
		- Continuous (T <sub>C</sub> = 100°C)	- Continuous ( $T_c = 100^{\circ}C$ )		
I <sub>DM</sub>	Drain Current	- Pulsed (N	lote 1)	46	Α
E <sub>AS</sub>	Single Pulsed Avalanch	e Energy (N	lote 2)	41	mJ
dv/dt	Peak Diode Recovery d	v/dt (M	Note 3)	6.0	V/ns
D	Dewer Dissignation	$(T_{\rm C} = 25^{\rm o}{\rm C})$		42	W
P <sub>D</sub>	Power Dissipation	- Derate Above 25°C		0.33	W/ºC
I <sub>F</sub> (AV)	Diode Average Rectified Forward Current (T <sub>C</sub> = 138°C)			5	Α
I <sub>FSM</sub>	Diode Non-repetitive Peak Surge Current 60 Hz Single Half-Sine Wave			50	Α
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage	Temperature Range		-55 to +150	°C
TL	Maximum Lead Temper	ature for Soldering, 1/8" from Case for 5 Se	conds	300	°C

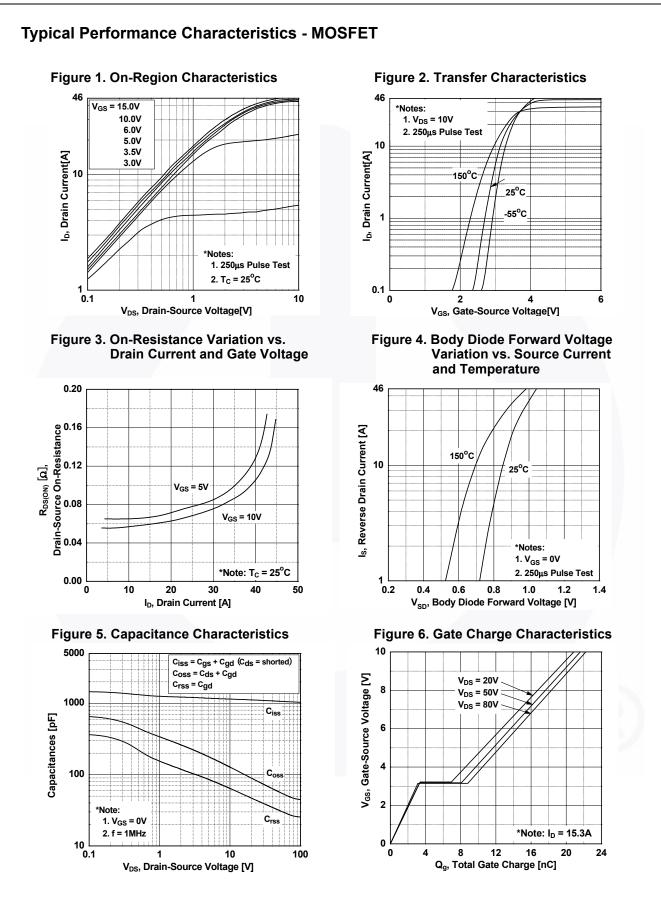
#### **Thermal Characteristics**

Symbol	Parameter	FDD850N10LD	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case for MOSFET, Max.	3.0	
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case for Diode, Max.	2.5	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient, Max.	87	

i art ituli	Part Number Top Mark		Package	ge Packing Method Reel Size		Тар	e Width	Qua	ntity
		TO-252 5	• •			6 mm	2500 units		
Electrica	I Char	acteristics of f	the MOSF	<b>ET</b> T <sub>C</sub> = 25°C unless	s otherwise not	ed.			
Symbol		Parameter		Test Conditi	ons	Min.	Тур.	Max.	Unit
Off Charac	teristic	S							
BV <sub>DSS</sub>	Drain to	Source Breakdown Vo	oltage	I <sub>D</sub> = 250 μA, V <sub>GS</sub> = 0 V			-	-	V
ΔBV <sub>DSS</sub> /ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient		ure	$I_D = 250 \ \mu\text{A}$ , Referenced to $25^{\circ}\text{C}$			0.1	-	V/ºC
I <sub>DSS</sub>	Zero Ga	ate Voltage Drain Curre	nt	$V_{DS}$ = 80 V, $V_{GS}$ = 0 V		-	-	1	μA
055	2010 00	Zero Gate Voltage Drain Current		$V_{DS} = 80 V, T_{C} = 125^{\circ}$		-	-	500	μΑ
I <sub>GSS</sub>	Gate to Body Leakage Current		t	$V_{GS}$ = ±20 V, $V_{DS}$ = 0 V	V	-	-	±100	nA
On Charac	teristics	5							
V <sub>GS(th)</sub>	Gate Th	nreshold Voltage		V <sub>GS</sub> = V <sub>DS</sub> , I <sub>D</sub> = 250 μ.	A	1.0	-	2.5	V
	Static Drain to Source On Resistance Forward Transconductance			$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 12 \text{ A}$		-	61	75	
R <sub>DS(on)</sub>			istance	$V_{GS} = 5 V, I_D = 12 A$			64	96	mΩ
9 <sub>FS</sub>				V <sub>DS</sub> = 10 V, I <sub>D</sub> = 15.3 A			31	-	S
Dynamic C	haracte	eristics					1		
C <sub>iss</sub>	1	apacitance		V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz		-	1100	1465	pF
C <sub>oss</sub>		Capacitance				-	80	105	pF
C <sub>rss</sub>		e Transfer Capacitance	•			-	42	-	pF
Q <sub>g(tot)</sub>		ate Charge at 10V		V <sub>DS</sub> = 80 V, I <sub>D</sub> = 15.3 A (Note 4)		-	22.2	28.9	nC
Q <sub>q(tot)</sub>	Total Ga	ate Charge at 5V				-	12.3	16.0	nC
Q <sub>gs</sub>		Source Gate Charge				-	3.0	-	nC
Q <sub>gd</sub>	Gate to	Drain "Miller" Charge				-	5.7	-	nC
ESR	Equivalent Series Resistance (G-S)		(G-S)	f = 1 MHz			1.75	-	Ω
Switching	Charac	teristics							
t <sub>d(on)</sub>	1	Delay Time					17	44	ns
t <sub>r</sub>		Rise Time		$V_{DD}$ = 50 V, I <sub>D</sub> = 15.3 A, V <sub>GS</sub> = 5 V, R <sub>G</sub> = 4.7 Ω			21	52	ns
t <sub>d(off)</sub>		f Delay Time				-	27	64	ns
t <sub>f</sub>		f Fall Time		(Note 4)			8	26	ns
		de Characteristic	6		. ,				
I <sub>s</sub>	1	m Continuous Drain to		ode Forward Current			-	15.3	A
I <sub>SM</sub>	Maximum Pulsed Drain to Source Diode I			Forward Current			-	46	Α
V <sub>SD</sub>	Drain to Source Diode Forward Voltage		d Voltage	V <sub>GS</sub> = 0 V, I <sub>SD</sub> = 12 A		-	-	1.3	V
t <sub>rr</sub>	Reverse	Recovery Time		$V_{GS} = 0 V, I_{SD} = 15.3 A, V_{DS} = 80 V,$		-	38	-	ns
Q <sub>rr</sub>	Reverse Recovery Charge			$dI_F/dt = 100 A/\mu s$		-	50	-	nC

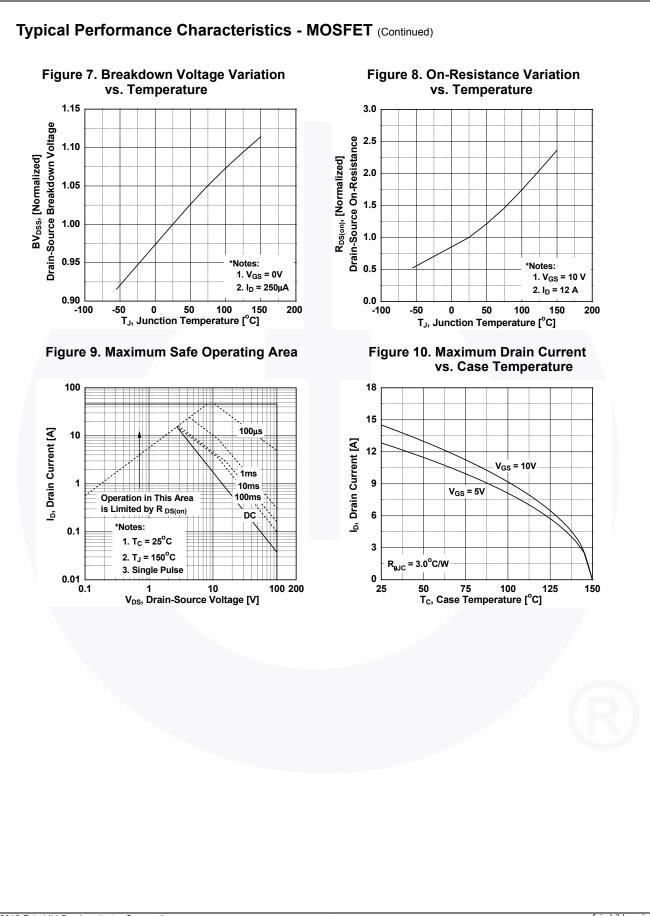
Symbol	Parameter Test Conditions		Min.	Тур.	Max.	Unit	
V <sub>R</sub>	DC Blocking Voltage	I <sub>R</sub> = 250 μA	150	-	-	V	
	Maximum Instantaneous Forward Voltage	I <sub>F</sub> = 5 A	T <sub>C</sub> = 25°C	-	-	2.5	v
			T <sub>C</sub> = 125°C	-	0.9	-	
	Maximum Instantaneous Reverse Current @ rated VR		T <sub>C</sub> = 25°C	-	-	50	
RM		Ly Taleu VR	T <sub>C</sub> = 125°C	-	-	1000	uA
+	Diode Reverse Recovery Time		T <sub>C</sub> = 25°C	-	10.7	22	20
۲r	Didde Reverse Recovery Time		T <sub>C</sub> = 125°C	-	14.5	-	ns
1		I <sub>F</sub> = 5 A, dI/dt = 200 A/μs	T <sub>C</sub> = 25°C	-	2.2	5	A
Irr	Didde Fear Reverse Recovery Current	ui/ut - 200 Α/μs	T <sub>C</sub> = 125°C	-	3.4	-	
0	Diode Reverse Recovery Charge		T <sub>C</sub> = 25°C	-	11.7	-	nC
Q <sub>rr</sub>	Didde Reverse Recovery Charge		T <sub>C</sub> = 125°C	-	24.7	-	
W <sub>AVL</sub>	Avalanche Energy (L = 40 mH)		10	-	-	mJ	

#### Electrical Characteristics of the Diode T<sub>C</sub> = 25°C unless otherwise noted.



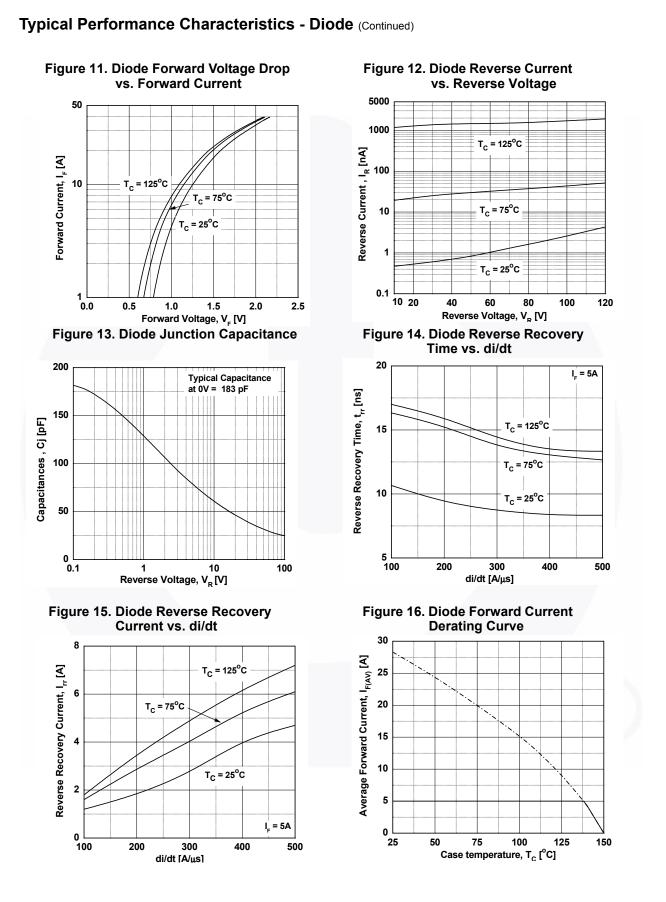
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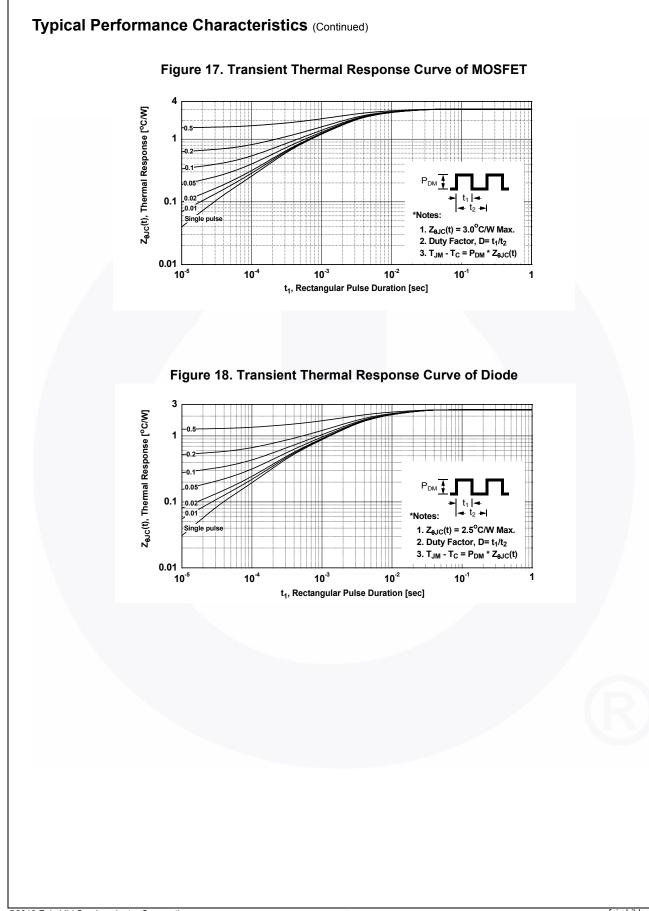


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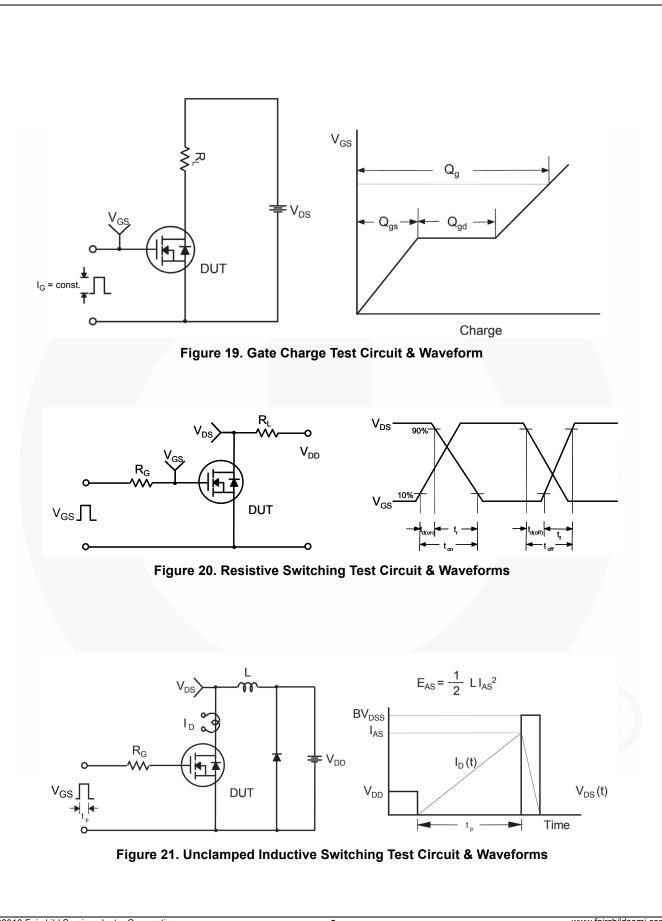
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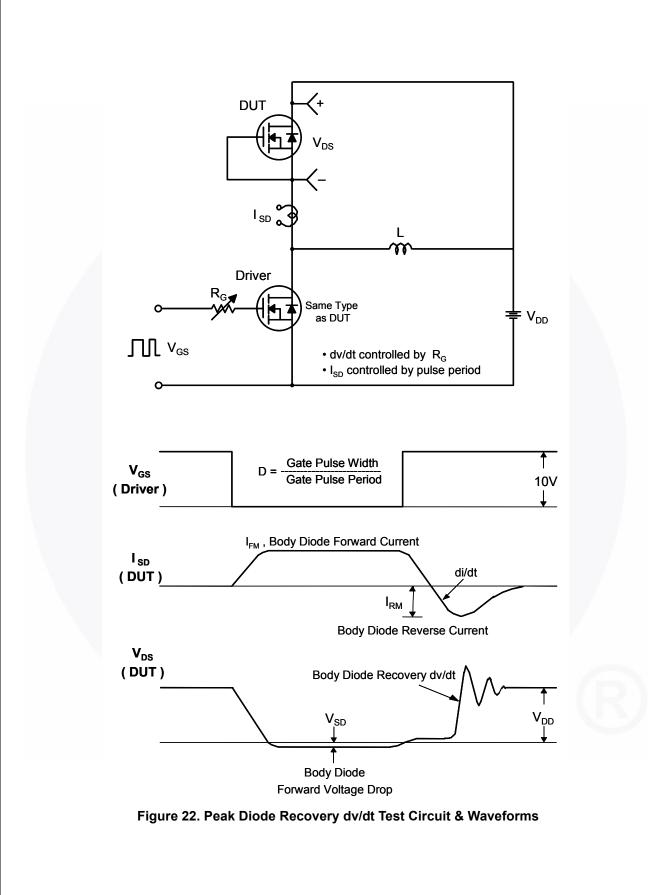


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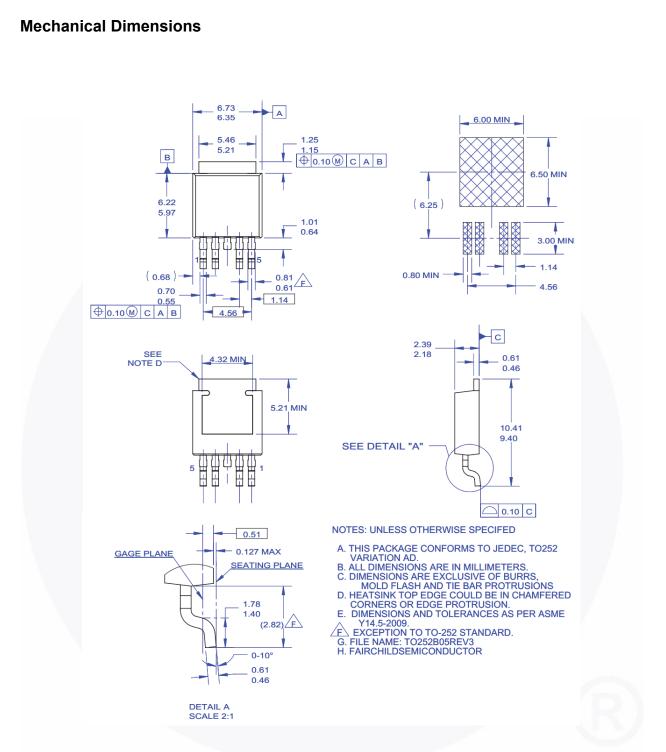


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#### Figure 23. TO252 (D-PAK), Molded, 5-Lead, Option AD

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